

# TIP29, A, B, C (NPN), TIP30, A, B, C (PNP)

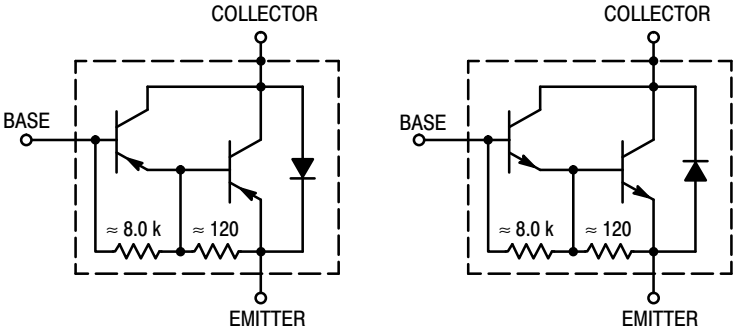


Figure 1. Darlington Circuit Schematic

## ORDERING INFORMATION

Device	Package	Shipping
TIP29	TO-220	50 Units / Rail
TIP29G	TO-220 (Pb-Free)	50 Units / Rail
TIP29A	TO-220	50 Units / Rail
TIP29AG	TO-220 (Pb-Free)	50 Units / Rail
TIP29B	TO-220	50 Units / Rail
TIP29BG	TO-220 (Pb-Free)	50 Units / Rail
TIP29C	TO-220	50 Units / Rail
TIP29CG	TO-220 (Pb-Free)	50 Units / Rail
TIP30	TO-220	50 Units / Rail
TIP30G	TO-220 (Pb-Free)	50 Units / Rail
TIP30A	TO-220	50 Units / Rail
TIP30AG	TO-220 (Pb-Free)	50 Units / Rail
TIP30B	TO-220	50 Units / Rail
TIP30BG	TO-220 (Pb-Free)	50 Units / Rail
TIP30C	TO-220	50 Units / Rail
TIP30CG	TO-220 (Pb-Free)	50 Units / Rail

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## ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Sustaining Voltage ( $I_C = 30\text{ mAdc}$ , $I_B = 0$ ) (Note 2)	$V_{CEO(sus)}$			Vdc
TIP29, TIP30		40	–	
TIP29A, TIP30A		60	–	
TIP29B, TIP30B		80	–	
TIP29C, TIP30C		100	–	
Collector Cutoff Current ( $V_{CE} = 30\text{ Vdc}$ , $I_B = 0$ ) ( $V_{CE} = 60\text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	–	0.3	mAdc
TIP29, TIP29A, TIP30, TIP30A		–	0.3	
TIP29B, TIP29C, TIP30B, TIP30C		–	0.3	
Collector Cutoff Current ( $V_{CE} = 40\text{ Vdc}$ , $V_{EB} = 0$ ) ( $V_{CE} = 60\text{ Vdc}$ , $V_{EB} = 0$ ) ( $V_{CE} = 80\text{ Vdc}$ , $V_{EB} = 0$ ) ( $V_{CE} = 100\text{ Vdc}$ , $V_{EB} = 0$ )	$I_{CES}$	–	200	$\mu\text{Adc}$
TIP29, TIP30		–	200	
TIP29A, TIP30A		–	200	
TIP29B, TIP30B		–	200	
TIP29C, TIP30C		–	200	
Emitter Cutoff Current ( $V_{BE} = 5.0\text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	–	1.0	mAdc

### ON CHARACTERISTICS (Note 2)

DC Current Gain ( $I_C = 0.2\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ ) ( $I_C = 1.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )	$h_{FE}$	40 15	– 75	–
Collector-Emitter Saturation Voltage ( $I_C = 1.0\text{ Adc}$ , $I_B = 125\text{ mAdc}$ )	$V_{CE(sat)}$	–	0.7	Vdc
Base-Emitter On Voltage ( $I_C = 1.0\text{ Adc}$ , $V_{CE} = 4.0\text{ Vdc}$ )	$V_{BE(on)}$	–	1.3	Vdc

### DYNAMIC CHARACTERISTICS

Current-Gain – Bandwidth Product (Note 3) ( $I_C = 200\text{ mAdc}$ , $V_{CE} = 10\text{ Vdc}$ , $f_{test} = 1.0\text{ MHz}$ )	$f_T$	3.0	–	MHz
Small-Signal Current Gain ( $I_C = 0.2\text{ Adc}$ , $V_{CE} = 10\text{ Vdc}$ , $f = 1.0\text{ kHz}$ )	$h_{fe}$	20	–	–

2. Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

3.  $f_T = |h_{fe}| \cdot f_{test}$

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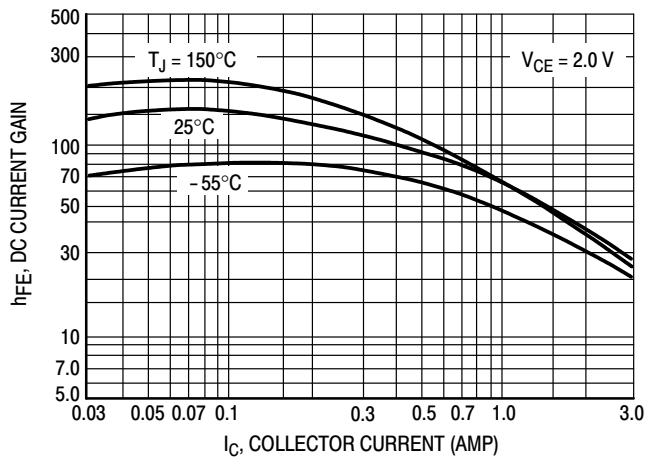


Figure 2. DC Current Gain

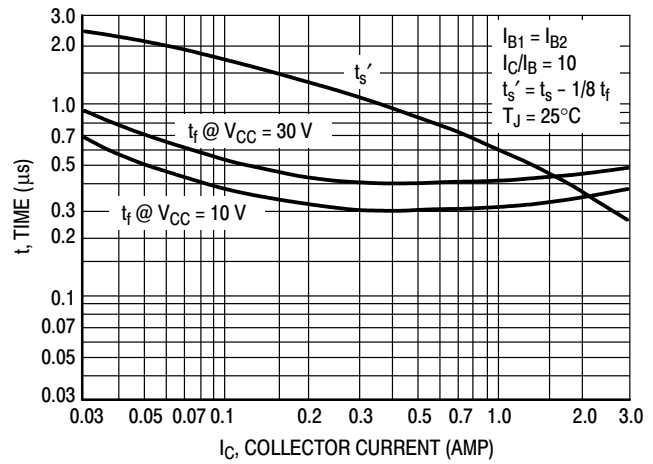


Figure 3. Turn-Off Time

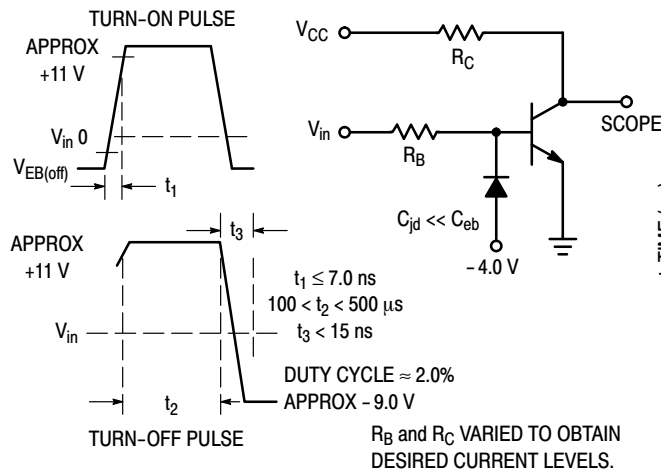


Figure 4. Switching Time Equivalent Circuit

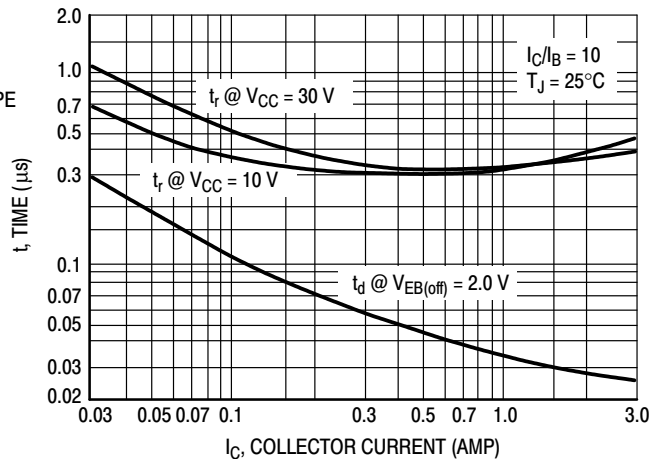


Figure 5. Turn-On Time

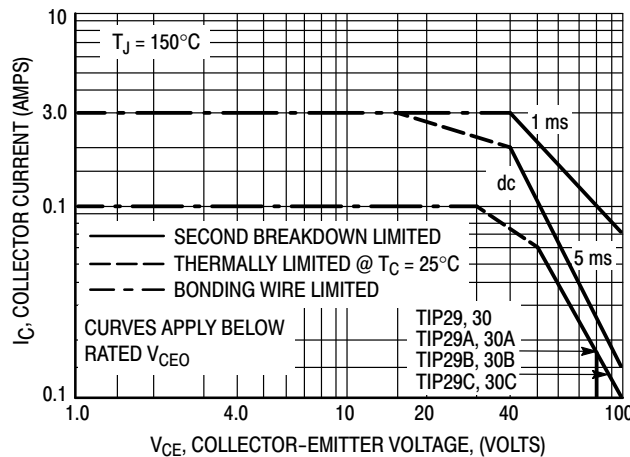


Figure 6. Active Region Safe Operating Area

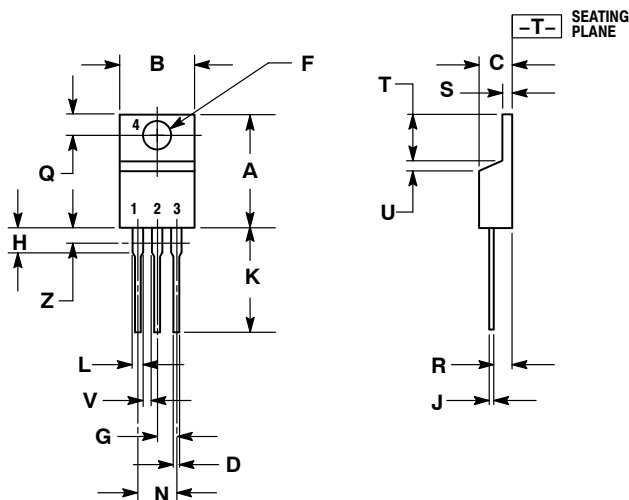
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on  $T_{J(pk)} = 150^\circ\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 150^\circ\text{C}$ . At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

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## PACKAGE DIMENSIONS

### TO-220 CASE 221A-09 ISSUE AG




#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.036	0.64	0.91
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
H	0.110	0.161	2.80	4.10
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

#### STYLE 1:

1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

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